

General Description

The MIC920 is a high-speed operational amplifier with a gain-bandwidth product of 80MHz. The part is unity gain stable. It has a very low 550 μ A supply current, and features the SC-70 package.

Supply voltage range is from $\pm 2.5V$ to $\pm 9V$, allowing the MIC920 to be used in low-voltage circuits or applications requiring large dynamic range.

The MIC920 is stable driving any capacitative load and achieves excellent PSRR and CMRR, making it much easier to use than most conventional high-speed devices. Low supply voltage, low power consumption, and small packing make the MIC920 ideal for portable equipment. The ability to drive capacitative loads also makes it possible to drive long coaxial cables.

Features

- 80MHz gain bandwidth product
- 115MHz –3dB bandwidth
- 550 μ A supply current
- SC-70 or SOT-23-5 packages
- 3000V/ μ s slew rate
- Drives any capacitive load
- Unity gain stable

Applications

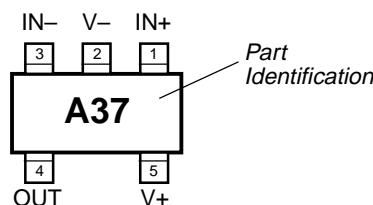
- Video
- Imaging
- Ultrasound
- Portable equipment
- Line drivers

Ordering Information

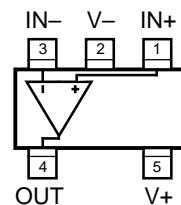
Part Number	Junction Temp. Range	Package
MIC920BM5	–40°C to +85°C	SOT-23-5*
MIC920BC5	–40°C to +85°C	SC-70

* Contact factory for availability of SOT-23-5 package.

Functional Pinout



SOT-23-5 or SC-70



SOT-23-5 or SC-70

Pin Description

Pin Number	Pin Name	Pin Function
1	IN+	Noninverting Input
2	V-	Negative Supply (Input)
3	IN-	Inverting Input
4	OUT	Output: Amplifier Output
5	V+	Positive Supply (Input)

Absolute Maximum Ratings (Note 1)

Supply Voltage ($V_{V+} - V_{V-}$)	20V
Differential Input Voltage ($ V_{IN+} - V_{IN-} $)	4V, Note 3
Input Common-Mode Range (V_{IN+}, V_{IN-})	V_{V+} to V_{V-}
Lead Temperature (soldering, 5 sec.)	260°C
Storage Temperature (T_S)	150°C
ESD Rating, Note 4	1.5kV

Operating Ratings (Note 2)

Supply Voltage (V_S)	$\pm 2.5V$ to $\pm 9V$
Junction Temperature (T_J)	-40°C to +85°C
Package Thermal Resistance	
SOT-23-5	260°C/W
SC-70-5	450°C/W

Electrical Characteristics ($\pm 5V$)

$V+ = +5V$, $V- = -5V$, $V_{CM} = 0V$, $R_L = 10M\Omega$; $T_J = 25^\circ C$, **bold** values indicate $-40^\circ C \leq T_J \leq +85^\circ C$; unless noted.

Symbol	Parameter	Condition	Min	Typ	Max	Units
V_{OS}	Input Offset Voltage			0.43	5	mV
V_{OS}	V_{OS} Temperature Coefficient			1		$\mu V/^\circ C$
I_B	Input Bias Current			0.26	0.6	μA
I_{OS}	Input Offset Current			0.04	0.3	μA
V_{CM}	Input Common-Mode Range	CMRR > 72dB	-3.25		+3.25	V
CMRR	Common-Mode Rejection Ratio	$-2.5V < V_{CM} < +2.5V$	75	85		dB
PSRR	Power Supply Rejection Ratio	$\pm 3.5V < V_S < \pm 9V$	95	104		dB
A_{VOL}	Large-Signal Voltage Gain	$R_L = 2k\Omega$, $V_{OUT} = \pm 2V$	65	82		dB
		$R_L = 100\Omega$, $V_{OUT} = \pm 1V$		85		dB
V_{OUT}	Maximum Output Voltage Swing	positive, $R_L = 2k\Omega$	+3.0	3.6		V
		negative, $R_L = 2k\Omega$		-3.6	-3.0	V
		positive, $R_L = 200\Omega$	+1.5	3.0		V
		negative, $R_L = 200\Omega$, Note 5		-2.5	-1.0	V
GBW	Unity Gain-Bandwidth Product	$C_L = 1.7pF$		67		MHz
PM	Phase Margin			32		°
BW	-3dB Bandwidth	$A_v = 1$, $R_L = 1k\Omega$, $C_L = 1.7pF$		100		MHz
SR	Slew Rate	$C=1.7pF$, Gain=1, $V_{OUT}=5V$, peak to peak, positive SR = 1190V/ μs		1350		V/ μs
I_{SC}	Short-Circuit Output Current	source	45	63		mA
		sink	20	45		mA
I_S	Supply Current	No Load		0.55	0.80	mA
	Input Voltage Noise	$f = 10kHz$		11		nV/\sqrt{Hz}
	Input Current Noise	$f = 10kHz$		0.7		pA/\sqrt{Hz}

Electrical Characteristics

$V+ = +9V$, $V- = -9V$, $V_{CM} = 0V$, $R_L = 10M\Omega$; $T_J = 25^\circ C$, **bold** values indicate $-40^\circ C \leq T_J \leq +85^\circ C$; unless noted

Symbol	Parameter	Condition	Min	Typ	Max	Units
V_{OS}	Input Offset Voltage			0.3	5	mV
V_{OS}	Input Offset Voltage Temperature Coefficient			1		$\mu V/^\circ C$
I_B	Input Bias Current			0.23	0.60	μA
I_{OS}	Input Offset Current			0.04	0.3	μA
V_{CM}	Input Common-Mode Range	CMRR > 75dB	-7.25		+7.25	V
CMRR	Common-Mode Rejection Ratio	$-6.5V < V_{CM} < +6.5V$	60	91		dB
PSRR	Power Supply Rejection Ratio	$\pm 3.5V < V_S < \pm 9V$	95	104		dB

Symbol	Parameter	Condition	Min	Typ	Max	Units
A_{VOL}	Large-Signal Voltage Gain	$R_L = 2k\Omega$, $V_{OUT} = \pm 2V$	75	84		dB
		$R_L = 100\Omega$, $V_{OUT} = \pm 1V$		93		dB
V_{OUT}	Maximum Output Voltage Swing	positive, $R_L = 2k\Omega$	6.5	7.5		V
		negative, $R_L = 2k\Omega$		-7.5	-6.2	V
GBW	Unity Gain-Bandwidth Product	$C_L = 1.7pF$		80		MHz
PM	Phase Margin			30		°
BW	-3dB Bandwidth	$A_V = 1$, $R_L = 1k\Omega$, $C_L = 1.7pF$		115		MHz
SR	Slew Rate	$C=1.7pF$, Gain=1, $V_{OUT}=5V$, peak to peak, negative SR = $2500V/\mu s$		3000		V/ μs
I_{SC}	Short-Circuit Output Current	source	50	65		mA
		sink	30	50		mA
I_S	Supply Current	No Load		0.55	0.8	mA
	Input Voltage Noise	$f = 10kHz$		10		nV/ \sqrt{Hz}
	Input Current Noise	$f = 10kHz$		0.8		pA/ \sqrt{Hz}

Note 1. Exceeding the absolute maximum rating may damage the device.

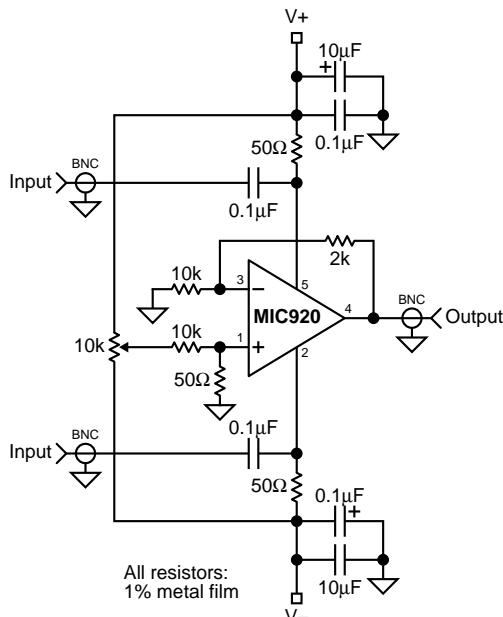
Note 2. The device is not guaranteed to function outside its operating rating.

Note 3. Exceeding the maximum differential input voltage will damage the input stage and degrade performance (in particular, input bias current is likely to change).

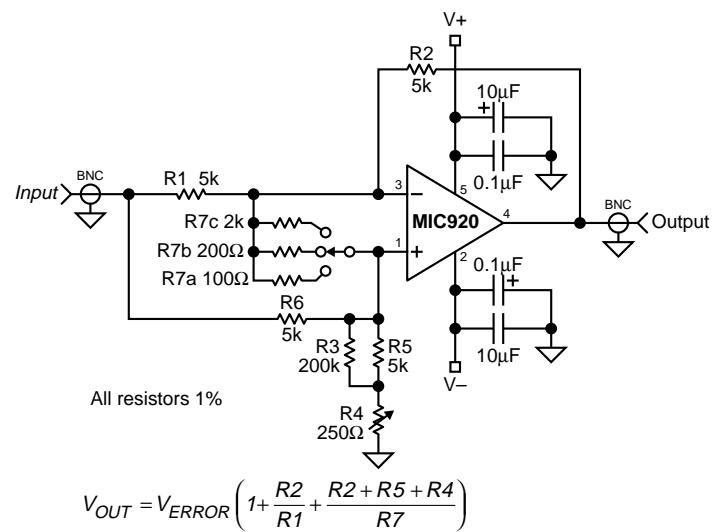
Note 4. Devices are ESD sensitive. Handling precautions recommended. Human body model, 1.5k in series with 100pF.

Note 5. Output swing limited by the maximum output sink capability, refer to the short-circuit current vs. temperature graph in "Typical Characteristics."

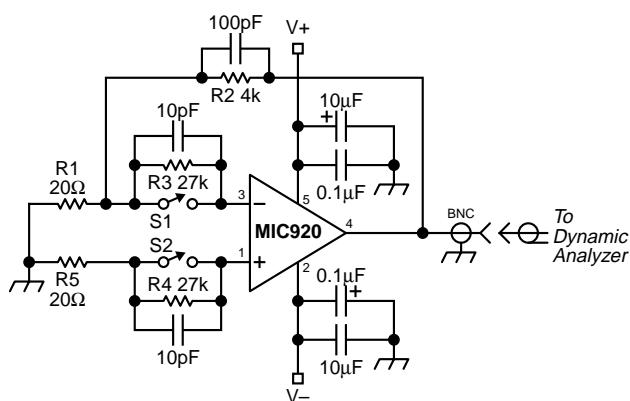
Test Circuits



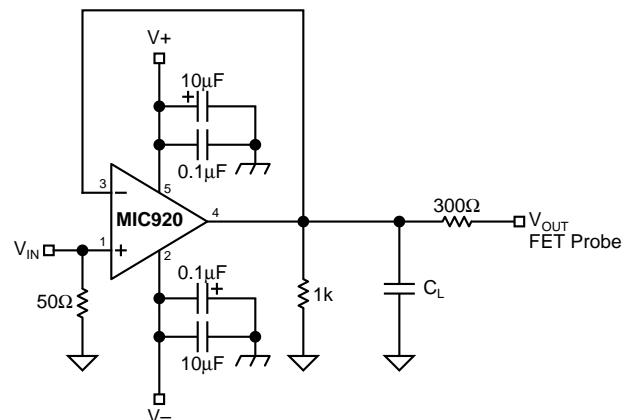
PSRR vs. Frequency



CMRR vs. Frequency

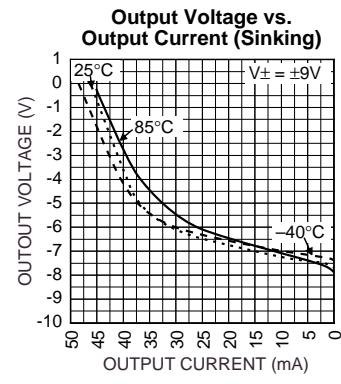
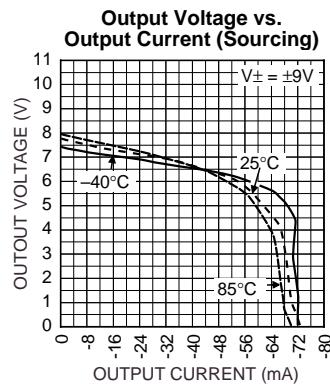
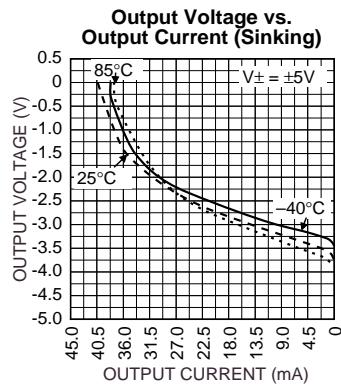
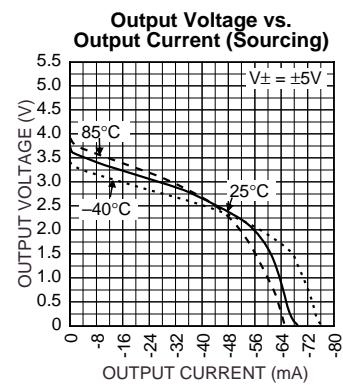
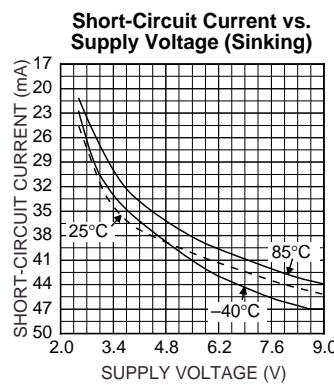
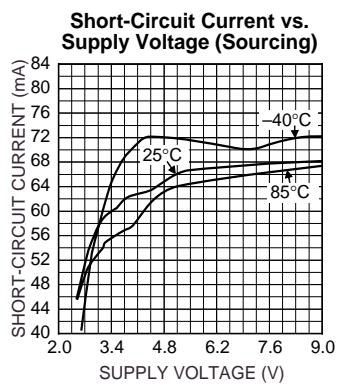
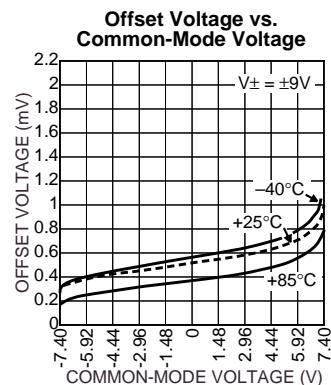
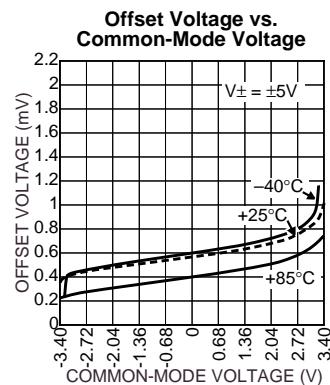
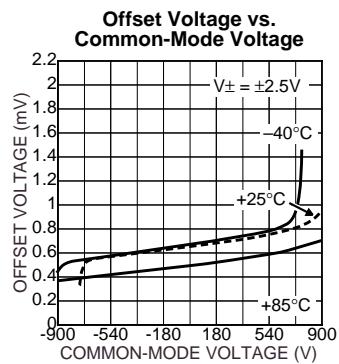
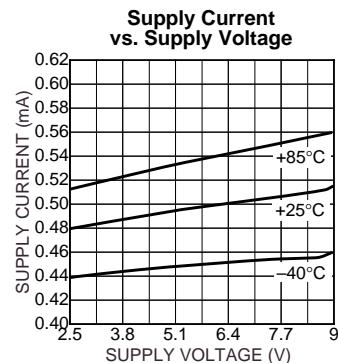
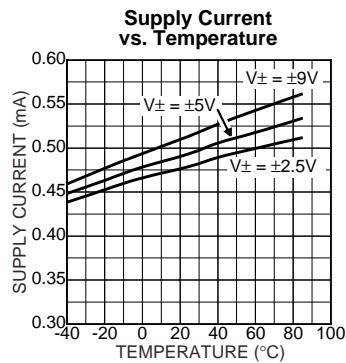
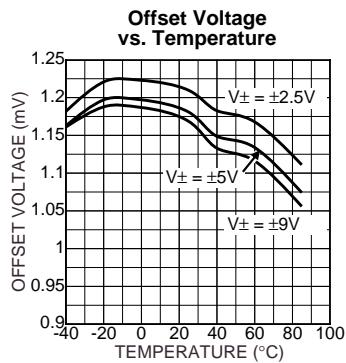


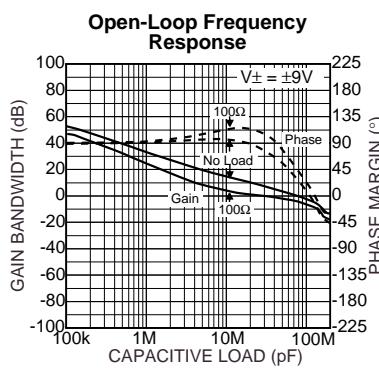
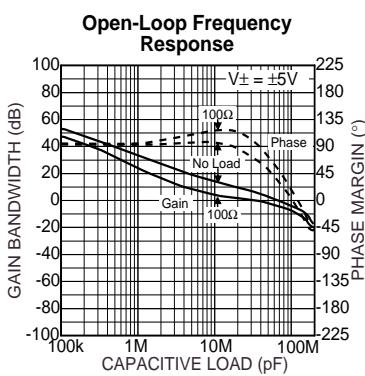
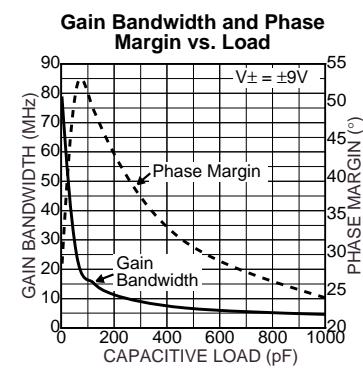
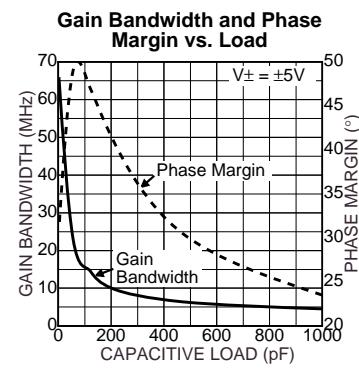
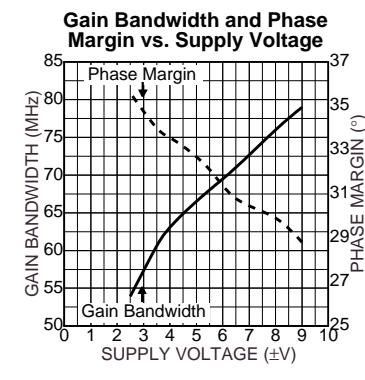
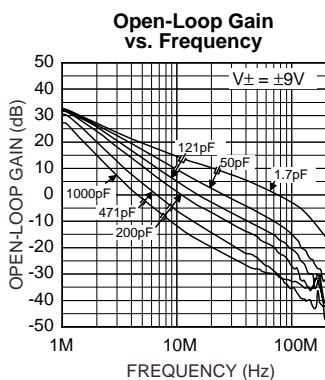
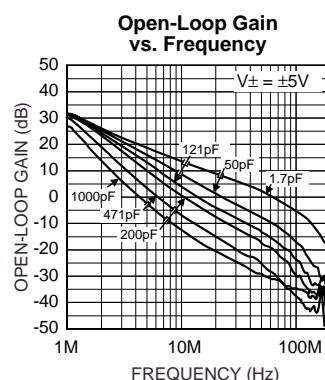
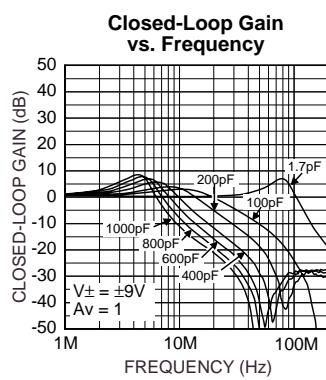
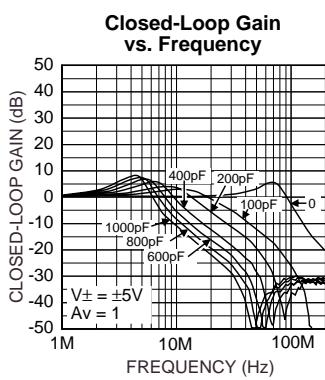
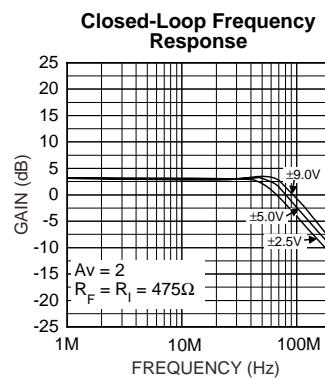
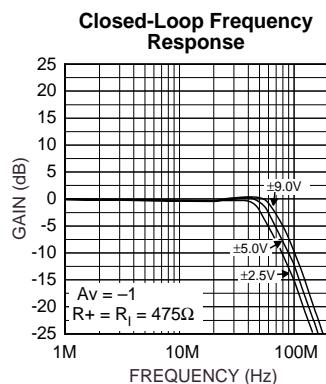
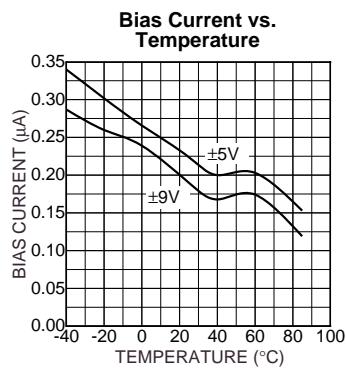
Noise Measurement

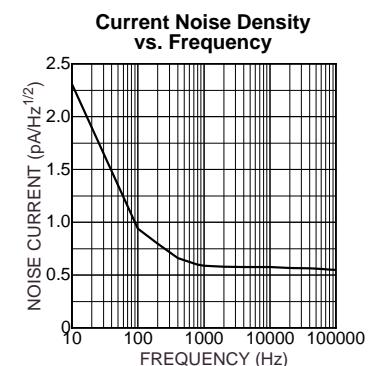
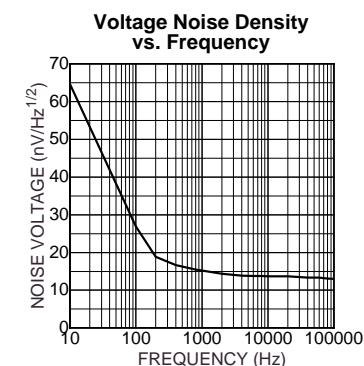
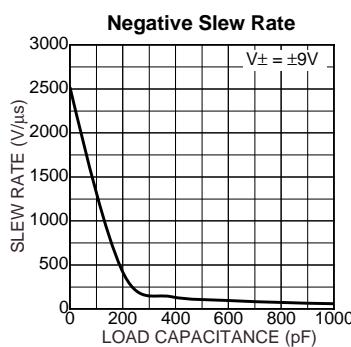
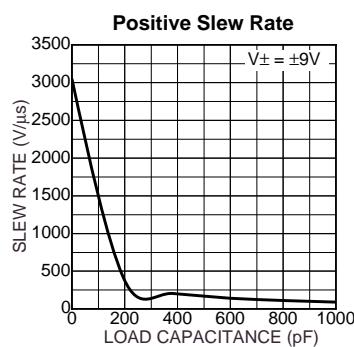
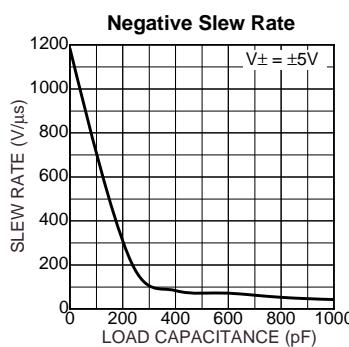
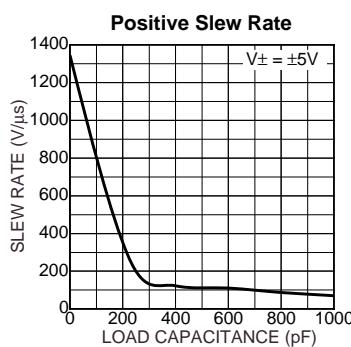
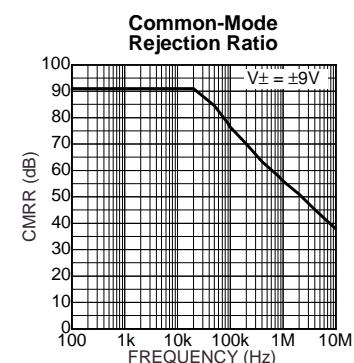
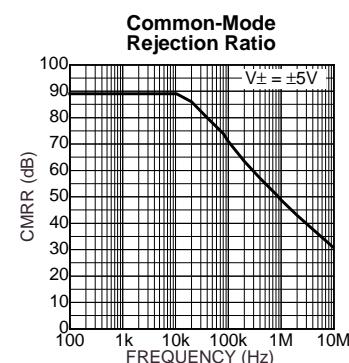
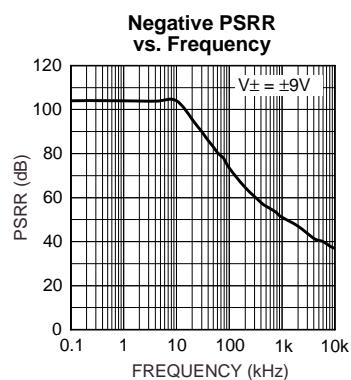
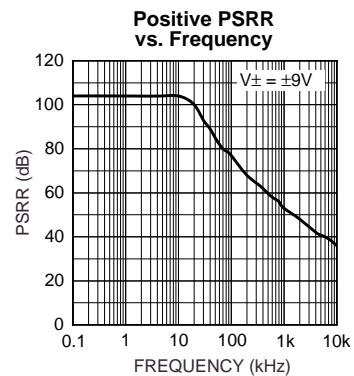
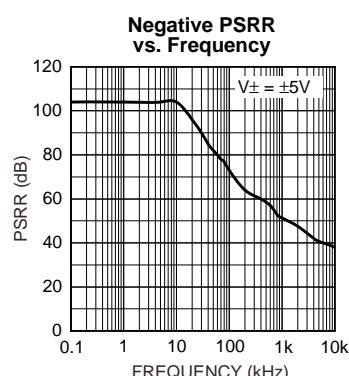
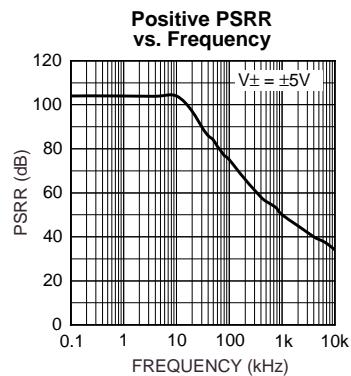


Closed Loop Frequency Response Measurement

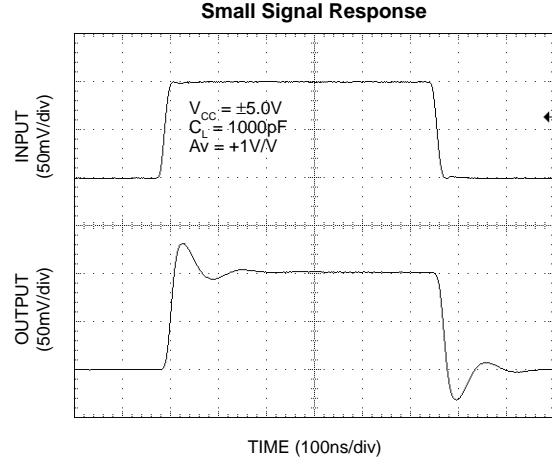
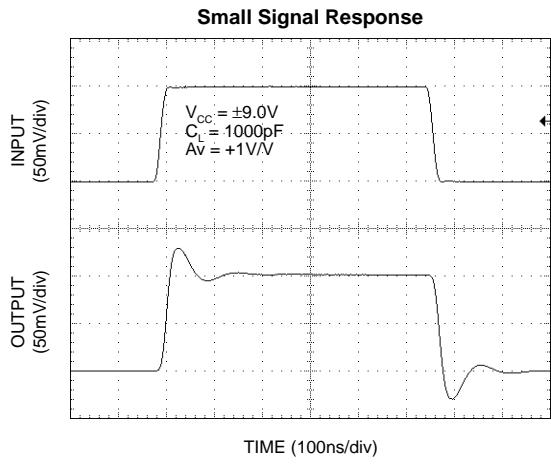
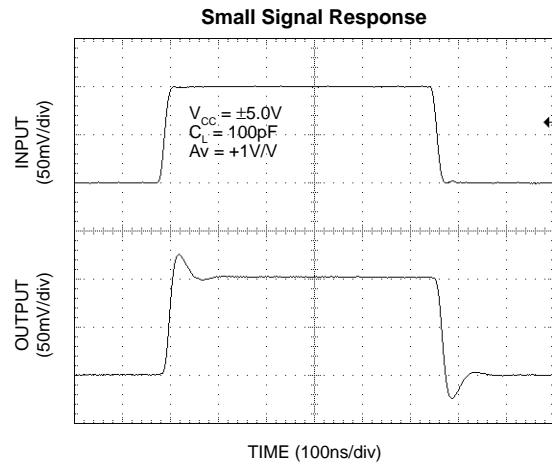
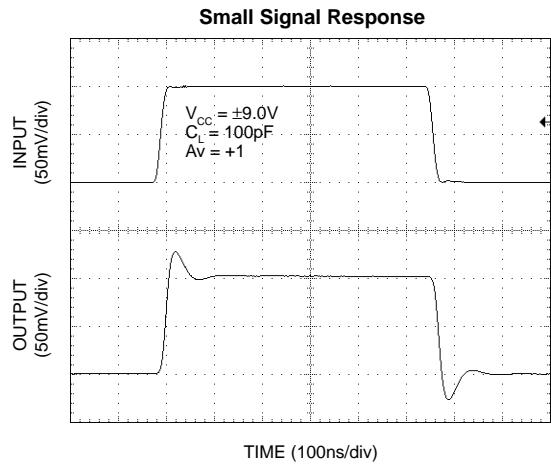
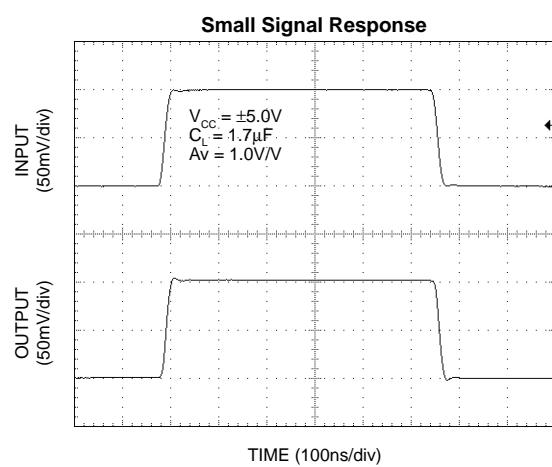
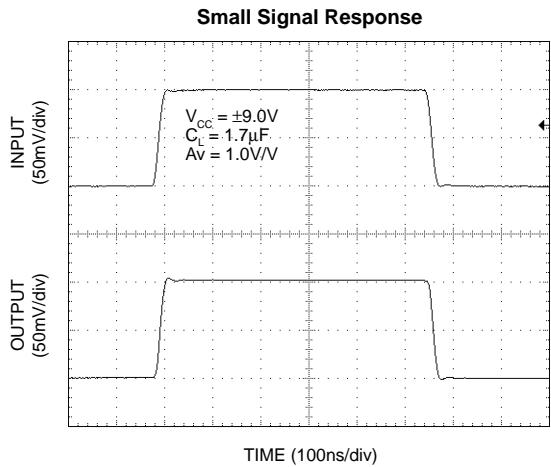
Typical Characteristics

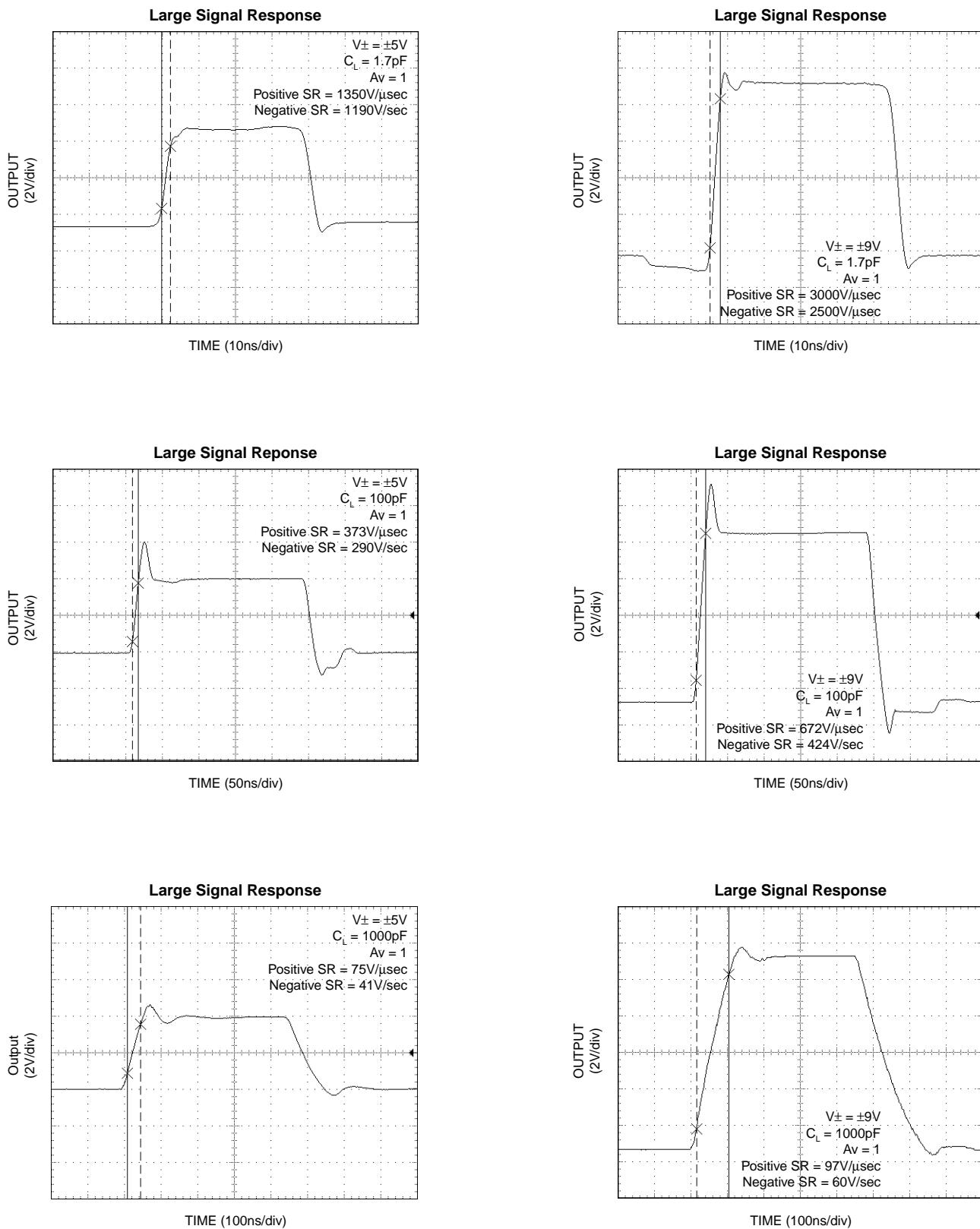






Functional Characteristics





Applications Information

The MIC920 is a high-speed, voltage-feedback operational amplifier featuring very low supply current and excellent stability. This device is unity gain stable, capable of driving high capacitance loads.

Driving High Capacitance

The MIC920 is stable when driving high capacitance, making it ideal for driving long coaxial cables or other high-capacitance loads. Most high-speed op amps are only able to drive limited capacitance.

Note: increasing load capacitance does reduce the speed of the device. In applications where the load capacitance reduces the speed of the op amp to an unacceptable level, the effect of the load capacitance can be reduced by adding a small resistor ($<100\Omega$) in series with the output.

Feedback Resistor Selection

Conventional op amp gain configurations and resistor selection apply, the MIC920 is NOT a current feedback device.

Also, for minimum peaking, the feedback resistor should have low parasitic capacitance, usually 470Ω is ideal. To use the part as a follower, the output should be connected to input via a short wire.

Layout Considerations

All high speed devices require careful PCB layout. The following guidelines should be observed: Capacitance, particularly on the two inputs pins will degrade performance; avoid large copper traces to the inputs. Keep the output signal away from the inputs and use a ground plane.

It is important to ensure adequate supply bypassing capacitors are located close to the device.

Power Supply Bypassing

Regular supply bypassing techniques are recommended. A $10\mu F$ capacitor in parallel with a $0.1\mu F$ capacitor on both the positive and negative supplies are ideal. For best performance all bypassing capacitors should be located as close to the op amp as possible and all capacitors should be low ESL (equivalent series inductance), ESR (equivalent series resistance). Surface-mount ceramic capacitors are ideal.

Thermal Considerations

The SC70-5 package and the SOT-23-5 package, like all small packages, have a high thermal resistance. It is important to ensure the IC does not exceed the maximum operating junction (die) temperature of $85^\circ C$. The part can be operated up to the absolute maximum temperature rating of $125^\circ C$, but between $85^\circ C$ and $125^\circ C$ performance will degrade, in particular CMRR will reduce.

An MIC920 with no load, dissipates power equal to the quiescent supply current \times supply voltage

$$P_{D(no\ load)} = (V_{V+} - V_{V-})I_S$$

When a load is added, the additional power is dissipated in the output stage of the op amp. The power dissipated in the device is a function of supply voltage, output voltage and output current.

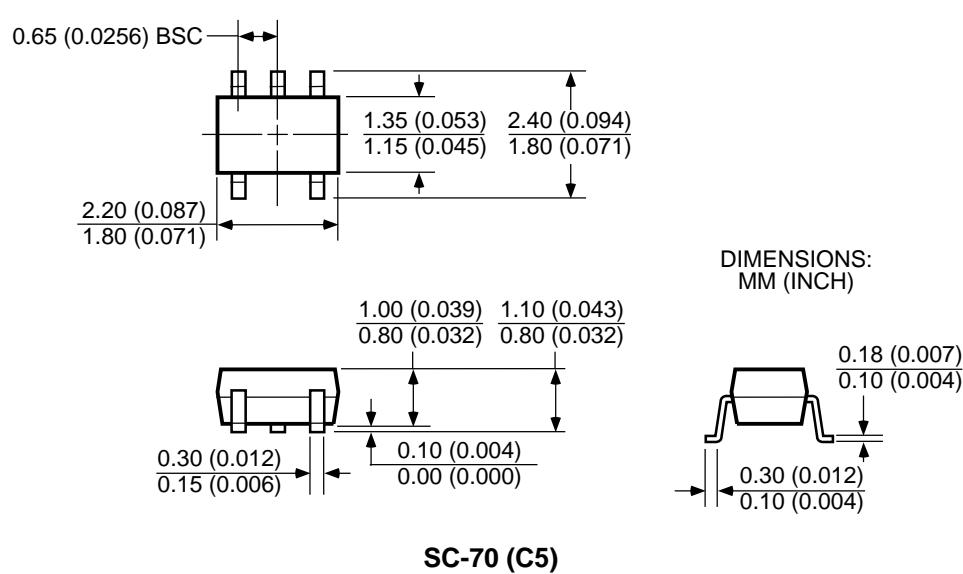
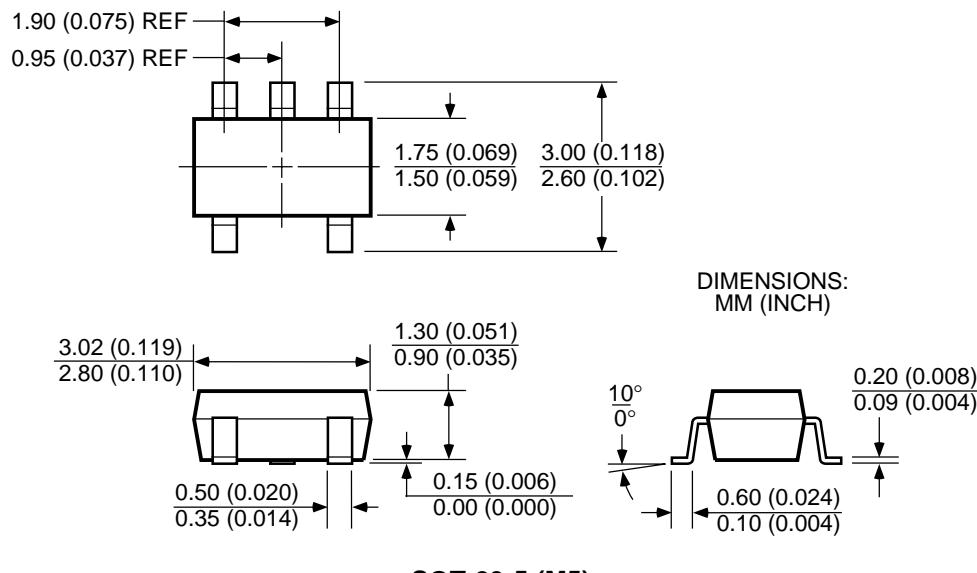
$$P_{D(output\ stage)} = (V_{V+} - V_{OUT})I_{OUT}$$

$$Total\ Power\ Dissipation = P_{D(no\ load)} + P_{D(output\ stage)}$$

Ensure the total power dissipated in the device is no greater than the thermal capacity of the package. The SC70-5 package has a thermal resistance of $450^\circ C/W$.

$$\text{Max. Allowable Power Dissipation} = \frac{T_{J(max)} - T_{A(max)}}{450^\circ C / W}$$

Package Information



MICREL INC. 1849 FORTUNE DRIVE SAN JOSE, CA 95131 USA

TEL + 1 (408) 944-0800 FAX + 1 (408) 944-0970 WEB <http://www.micrel.com>

This information is believed to be accurate and reliable, however no responsibility is assumed by Micrel for its use nor for any infringement of patents or other rights of third parties resulting from its use. No license is granted by implication or otherwise under any patent or patent right of Micrel Inc.

© 2001 Micrel Incorporated